

**MOTOROLA  
SEMICONDUCTOR**  
TECHNICAL DATA

**MC1411,B  
MC1412,B  
MC1413,B  
MC1416,B**

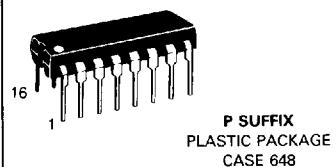
**HIGH VOLTAGE, HIGH CURRENT  
DARLINGTON TRANSISTOR ARRAYS**

The seven NPN Darlington connected transistors in these arrays are well suited for driving lamps, relays, or printer hammers in a variety of industrial and consumer applications. Their high breakdown voltage and internal suppression diodes insure freedom from problems associated with inductive loads. Peak inrush currents to 600 mA permit them to drive incandescent lamps.

The MC1411,B device is a general purpose array for use with DTL, TTL, PMOS, or CMOS Logic. The MC1412,B contains a zener diode and resistor in series with the input to limit input current for use with 14 to 25 Volt PMOS Logic. The MC1413,B with a 2.7 k $\Omega$  series input resistor is well suited for systems utilizing a 5 Volt TTL or CMOS Logic. The MC1416,B uses a series 10.5 k $\Omega$  resistor and is useful in 8 to 18 Volt MOS systems.

**PERIPHERAL  
DRIVER ARRAYS**

SILICON MONOLITHIC  
INTEGRATED CIRCUITS



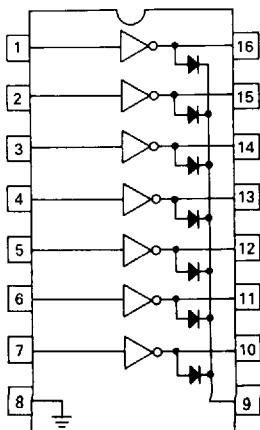
**MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$  and rating apply to any one device in the package unless otherwise noted)

Rating	Symbol	Value	Unit
Output Voltage	$V_O$	50	V
Input Voltage (Except MC1411)	$V_I$	30	V
Collector Current — Continuous	$I_C$	500	mA
Base Current — Continuous	$I_B$	25	mA
Operating Ambient Temperature Range MC1411-16 MC1411B-16B	$T_A$	-20 to +85 -40 to +85	°C
Storage Temperature Range	$T_{stg}$	-55 to +150	°C
Junction Temperature	$T_J$	150	°C
Thermal Resistance — Junction-to-Ambient Case 648, P Suffix Case 751B, D Suffix	$\theta_{JA}$	67 100	°C/W

**ORDERING INFORMATION**

Plastic DIP	SOIC	Ambient Temperature Range
MC1411P (ULN2001A)	MC1411D	
MC1412P (ULN2002A)	MC1412D	
MC1413P (ULN2003A)	MC1413D	
MC1416P (ULN2004A)	MC1416D	
MC1411BP	MC1411BD	
MC1412BP	MC1412BD	
MC1413BP	MC1413BD	
MC1416BP	MC1416BD	
		-40° to +85°C

**PIN CONNECTIONS**



## MC1411,B, MC1412,B, MC1413,B, MC1416,B

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit	
Output Leakage Current ( $V_O = 50 \text{ V}$ , $T_A = +85^\circ\text{C}$ ) ( $V_O = 50 \text{ V}$ , $T_A = +25^\circ\text{C}$ ) ( $V_O = 50 \text{ V}$ , $T_A = +85^\circ\text{C}$ , $V_I = 6.0 \text{ V}$ ) ( $V_O = 50 \text{ V}$ , $T_A = +85^\circ\text{C}$ , $V_I = 1.0 \text{ V}$ )	$I_{CEX}$	—	—	100	$\mu\text{A}$	
All Types		—	—	50		
All Types		—	—	500		
MC1412,B MC1416,B		—	—	500		
Collector-Emitter Saturation Voltage ( $I_C = 350 \text{ mA}$ , $I_B = 500 \mu\text{A}$ ) ( $I_C = 200 \text{ mA}$ , $I_B = 350 \mu\text{A}$ ) ( $I_C = 100 \text{ mA}$ , $I_B = 250 \mu\text{A}$ )	$V_{CE(\text{sat})}$	—	1.1	1.6	V	
All Types		—	0.95	1.3		
All Types		—	0.85	1.1		
Input Current — On Condition ( $V_I = 17 \text{ V}$ ) ( $V_I = 3.85 \text{ V}$ ) ( $V_I = 5.0 \text{ V}$ ) ( $V_I = 12 \text{ V}$ )	$I_{I(\text{on})}$	—	0.85	1.3	$\text{mA}$	
MC1412,B		—	0.93	1.35		
MC1413,B		—	0.35	0.5		
MC1416,B		—	1.0	1.45		
Input Voltage — On Condition ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 300 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 200 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 250 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 300 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 125 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 200 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 275 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 350 \text{ mA}$ )	$V_{I(\text{on})}$	—	—	13	V	
MC1412,B		—	—	2.4		
MC1413,B		—	—	2.7		
MC1413,B		—	—	3.0		
MC1413,B		—	—	5.0		
MC1416,B		—	—	6.0		
MC1416,B		—	—	7.0		
MC1416,B		—	—	8.0		
Input Current — Off Condition ( $I_C = 500 \mu\text{A}$ , $T_A = +85^\circ\text{C}$ )	All Types	$I_{I(\text{off})}$	50	100	—	$\mu\text{A}$
DC Current Gain ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 350 \text{ mA}$ )	MC1411,B	$h_{FE}$	1000	—	—	—
Input Capacitance		$C_I$	—	15	30	$\text{pF}$
Turn-On Delay Time (50% $E_I$ to 50% $E_O$ )		$t_{on}$	—	0.25	1.0	$\mu\text{s}$
Turn-Off Delay Time (50% $E_I$ to 50% $E_O$ )		$t_{off}$	—	0.25	1.0	$\mu\text{s}$
Clamp Diode Leakage Current ( $V_R = 50 \text{ V}$ )	$T_A = +25^\circ\text{C}$ $T_A = +85^\circ\text{C}$	$I_R$	—	—	50	$\mu\text{A}$
			—	—	100	
Clamp Diode Forward Voltage ( $I_F = 350 \text{ mA}$ )		$V_F$	—	1.5	2.0	V

TYPICAL PERFORMANCE CURVES —  $T_A = 25^\circ\text{C}$ 

FIGURE 1 — OUTPUT CURRENT versus INPUT VOLTAGE

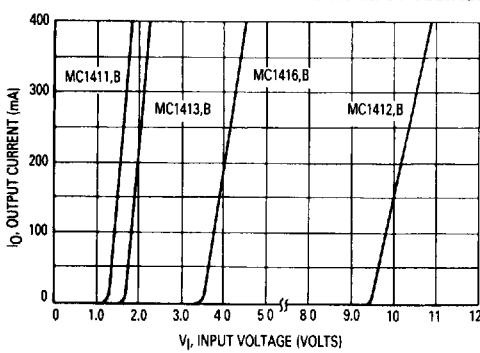
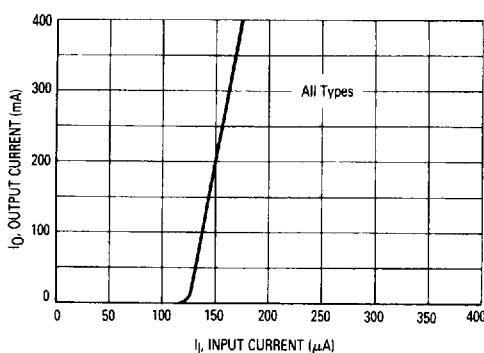
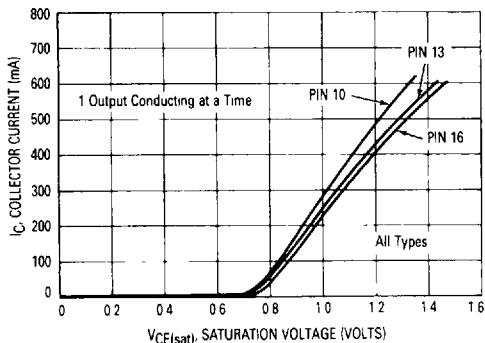
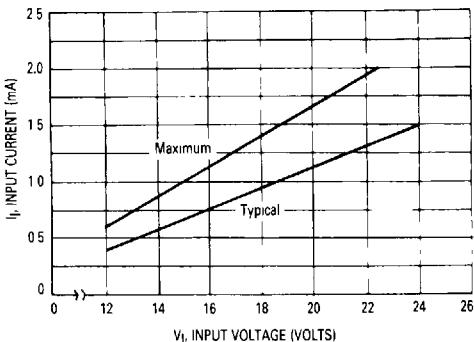
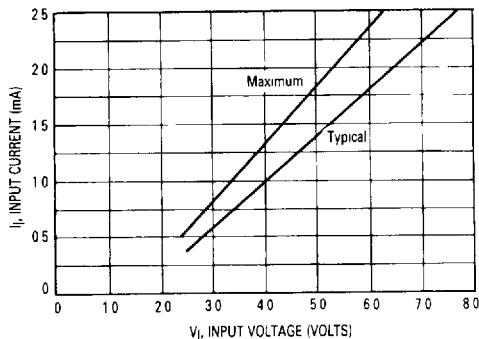
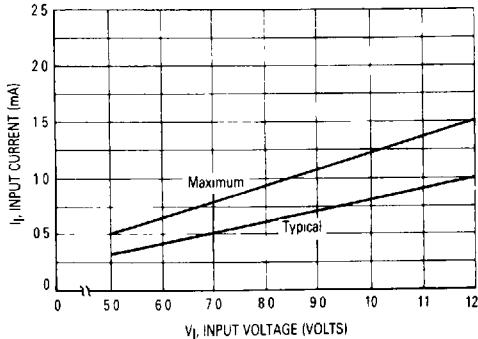
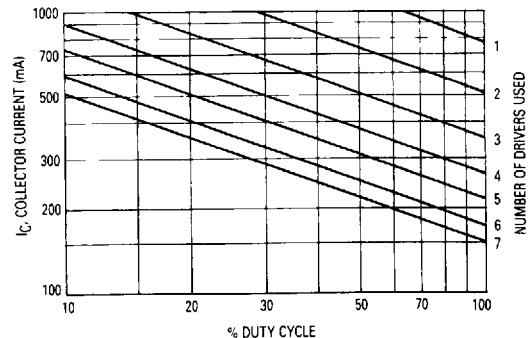


FIGURE 2 — OUTPUT CURRENT versus INPUT CURRENT



**MC1411,B, MC1412,B, MC1413,B, MC1416,B****TYPICAL CHARACTERISTIC CURVES –  $T_A = 25^\circ\text{C}$  (continued)****FIGURE 3 — TYPICAL OUTPUT CHARACTERISTICS****FIGURE 4 — INPUT CHARACTERISTICS — MC1412,B****FIGURE 5 — INPUT CHARACTERISTICS — MC1413,B****FIGURE 6 — INPUT CHARACTERISTICS — MC1416,B**

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**FIGURE 7 — MAXIMUM COLLECTOR CURRENT  
versus DUTY CYCLE  
(AND NUMBER OF DRIVERS IN USE)**

**MC1411,B, MC1412,B, MC1413,B, MC1416,B**

FIGURE 8 — REPRESENTATIVE CIRCUIT SCHEMATICS

